Low-power D-type flip-flop with set and reset; positive-edge trigger Rev. 4.1 — 9 August 2024

Product data sheet

1. General description

The 74AUP1G74-Q100 is a single positive edge triggered D-type flip-flop with individual data (D), clock (CP), set (\overline{SD}) and reset (\overline{RD}) inputs, and complementary Q and \overline{Q} outputs. Data at the D-input that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition will be stored in the flip-flop and appear at the Q output.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low noise overshoot and undershoot < 10 % of V_{CC}
- IOFF circuitry provides partial Power-down mode operation
 - Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

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3. Ordering information

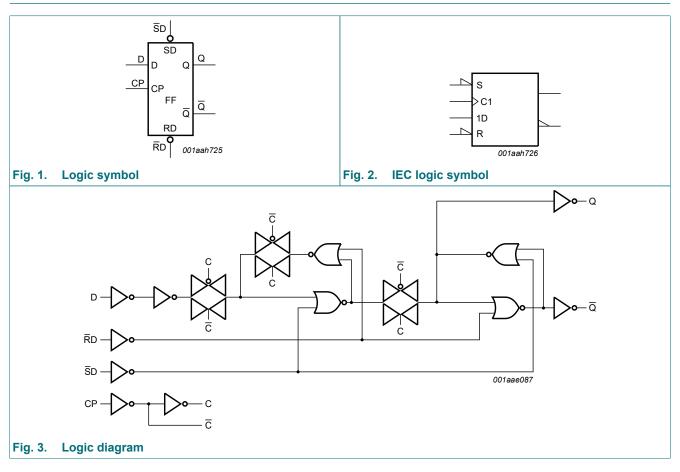
Table 1. Ordering information									
Type number Package									
	Temperature range	Name	Description	Version					
74AUP1G74DC-Q100	-40 °C to +125 °C		plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	<u>SOT765-1</u>					

4. Marking

Fable 2. Marking codes	
Type number	Marking code[1]
74AUP1G74DC-Q100	p74

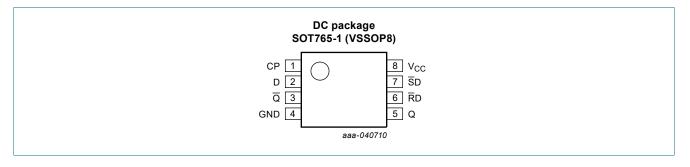
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin descrip	otion	
Symbol	Pin	Description
СР	1	clock input
D	2	data input
Q	3	complement output
GND	4	ground (0 V)
Q	5	true output
RD	6	asynchronous reset input (active LOW)
SD	7	asynchronous set input (active LOW)
V _{CC}	8	supply voltage

7. Functional description

Table 4. Function table for asynchronous operation

H = *HIGH* voltage level; *L* = *LOW* voltage level; *X* = don't care.

Input		Output			
<u>S</u> D	RD	СР	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	Н	Н

Table 5. Function table for synchronous operation

H = HIGH voltage level; L = LOW voltage level; $\uparrow = LOW$ -to-HIGH CP transition;

 \overline{Q}_{n+1} , Q_{n+1} = state after the next LOW-to-HIGH CP transition.

Input		Output			
SD	RD	CP D C		Q _{n+1}	Q n+1
Н	Н	1	L	L	Н
Н	Н	1	Н	Н	L

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	[1]	-0.5	+4.6	V
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I _{ОК}	output clamping current	V _O < 0 V	-50	-	mA
lo	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C			
		SOT765-1 (VSSOP8) [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

9. Recommended operating conditions

Table 7. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
T _{amb} = 25	T _{amb} = 25 °C								
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V			
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V			
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V			
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V			
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V			
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V			
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V			
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V			

Symbol			Min	Тур	Мах	Unit
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I_0 = -4.0 mA; V_{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_0 = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; $ [1] $V_{CC} = 3.3 \text{ V}; \text{ per pin}$	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.6	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	1.3	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C				1	
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_0 = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.5	μA
∆I _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; $ [1] $V_{CC} = 3.3 \text{ V}; \text{ per pin}$	-	-	50	μA

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +125 °C					1
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.6 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ [1] $V_{CC} = 3.3 V; per pin$	-	-	75	μA

Low-power D-type flip-flop with set and reset; positive-edge trigger

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions	Т	_{amb} = 25	°C	T _{ar} -40 °C t	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F	1					·			
t _{pd}	propagation delay	CP to Q, \overline{Q} ; see Fig. 4.	2]							
		V _{CC} = 0.8 V	-	25.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	6.7	14.0	2.6	14.2	2.6	14.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.5	7.6	2.3	8.3	2.3	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.5	5.7	1.7	6.5	1.7	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.6	3.8	1.4	4.4	1.4	4.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	2.2	3.1	1.2	3.4	1.2	3.7	ns
		\overline{SD} to Q, \overline{Q} ; see <u>Fig. 5</u> .	2]							
		V _{CC} = 0.8 V	-	19.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	5.6	11.0	2.5	11.4	2.5	11.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.0	6.3	2.2	6.9	2.2	7.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.3	4.9	1.7	5.6	1.7	5.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	2.7	3.7	1.7	4.0	1.7	4.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.5	3.2	1.5	3.6	1.5	3.8	ns
		$\overline{R}D$ to Q, \overline{Q} ; see <u>Fig. 5</u> .	2]							
		V _{CC} = 0.8 V	-	19.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	5.5	11.0	2.5	11.3	2.5	11.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	3.9	6.3	2.2	6.8	2.2	7.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	5.0	1.8	5.6	1.8	5.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	2.6	3.6	1.7	4.1	1.7	4.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.4	3.3	1.5	3.6	1.5	3.8	ns
f _{max}	maximum	CP; see <u>Fig. 4</u> .								
	frequency	V _{CC} = 0.8 V	-	53	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	203	-	170	-	170	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	347	-	310	-	300	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	435	-	400	-	390	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	550	-	490	-	480	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	619	-	550	-	510	-	MHz

Symbol	Parameter	Conditions		T,	amb = 25 '	°C	T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 10	pF								-		
t _{pd}		CP to Q, \overline{Q} ; see Fig. 4.	[2]								
	delay	V _{CC} = 0.8 V		-	28.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.1	7.5	15.8	2.9	16.1	2.9	16.1	ns
		V _{CC} = 1.4 V to 1.6 V		2.7	5.1	8.7	2.4	9.4	2.4	9.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.5	4.1	6.5	2.2	7.2	2.2	7.6	ns
		V _{CC} = 2.3 V to 2.7 V		2.0	3.2	4.6	1.8	5.3	1.8	5.6	ns
		V _{CC} = 3.0 V to 3.6 V		1.8	2.8	3.8	1.6	4.1	1.6	4.4	ns
		SD to Q, Q; see <u>Fig. 5</u> .	[2]								
		V _{CC} = 0.8 V		-	23.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.9	6.5	12.9	2.8	13.3	2.8	13.5	ns
		V _{CC} = 1.4 V to 1.6 V		2.7	4.6	7.5	2.3	7.9	2.3	8.3	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	3.9	5.6	2.3	6.3	2.3	6.6	ns
		V _{CC} = 2.3 V to 2.7 V		2.3	3.2	4.4	2.0	4.8	2.0	5.2	ns
		V _{CC} = 3.0 V to 3.6 V		2.2	3.0	3.9	1.9	4.2	1.9	4.4	ns
		$\overline{R}D$ to Q, \overline{Q} ; see <u>Fig. 5</u> .	[2]								
		V _{CC} = 0.8 V		-	22.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.8	6.4	12.8	2.7	13.2	2.7	13.4	ns
		V _{CC} = 1.4 V to 1.6 V		2.6	4.5	7.5	2.3	8.1	2.3	8.4	ns
		V _{CC} = 1.65 V to 1.95 V		2.5	3.3	5.8	2.3	6.3	2.3	6.7	ns
		V _{CC} = 2.3 V to 2.7 V		2.2	3.2	4.4	2.0	4.9	2.0	5.2	ns
		V _{CC} = 3.0 V to 3.6 V		2.0	2.9	4.0	1.9	4.3	1.9	4.5	ns
f _{max}	maximum	CP; see <u>Fig. 4</u> .									
	frequency	V _{CC} = 0.8 V		-	52	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V		-	192	-	150	-	150	-	MHz
		V _{CC} = 1.4 V to 1.6 V		-	324	-	280	-	230	-	MHz
		V _{CC} = 1.65 V to 1.95 V		-	421	-	310	-	250	-	MHz
		V _{CC} = 2.3 V to 2.7 V		-	486	-	370	-	360	-	MHz
		V _{CC} = 3.0 V to 3.6 V		-	550	-	410	-	360	-	MHz

Symbol	Parameter	Conditions		T,	amb = 25	°C	T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Мах	Min	Max	
C _L = 15	pF										
t _{pd}		CP to Q, \overline{Q} ; see Fig. 4.	[2]								
	delay	V _{CC} = 0.8 V		-	32.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.5	8.3	17.6	3.3	17.8	3.3	18.0	ns
		V _{CC} = 1.4 V to 1.6 V		3.2	5.6	9.5	2.8	10.5	2.8	11.1	ns
		V _{CC} = 1.65 V to 1.95 V		2.7	4.6	7.2	2.5	8.1	2.5	8.6	ns
		V _{CC} = 2.3 V to 2.7 V		2.4	3.6	5.2	2.2	5.8	2.2	6.2	ns
		V _{CC} = 3.0 V to 3.6 V		2.2	3.2	4.4	2.0	4.9	2.0	5.2	ns
		SD to Q, Q; see <u>Fig. 5</u> .	[2]								
		V _{CC} = 0.8 V		-	26.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.3	7.3	14.7	3.1	15.2	3.1	15.4	ns
		V _{CC} = 1.4 V to 1.6 V		3.2	5.2	8.3	2.9	9.0	2.9	9.5	ns
		V _{CC} = 1.65 V to 1.95 V		2.8	4.3	6.4	2.5	7.1	2.5	7.5	ns
		V _{CC} = 2.3 V to 2.7 V		2.8	3.7	5.1	2.2	5.5	2.2	5.8	ns
		V _{CC} = 3.0 V to 3.6 V		2.5	3.5	4.6	2.4	5.0	2.4	5.2	ns
		$\overline{R}D$ to Q, \overline{Q} ; see <u>Fig. 5</u> .	[2]								
		V _{CC} = 0.8 V		-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.2	7.2	14.5	3.1	15.0	3.1	15.2	ns
		V _{CC} = 1.4 V to 1.6 V		3.1	5.1	8.4	2.7	9.2	2.7	9.7	ns
		V _{CC} = 1.65 V to 1.95 V		2.7	4.3	6.5	2.6	7.3	2.6	7.7	ns
		V _{CC} = 2.3 V to 2.7 V		2.6	3.6	5.0	2.4	5.5	2.4	5.8	ns
		V _{CC} = 3.0 V to 3.6 V		2.4	3.4	4.6	2.3	5.0	2.3	5.2	ns
f _{max}	maximum	CP; see <u>Fig. 4</u> .									
	frequency	V _{CC} = 0.8 V		-	50	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V		-	181	-	120	-	120	-	MHz
		V _{CC} = 1.4 V to 1.6 V		-	301	-	190	-	160	-	MHz
		V _{CC} = 1.65 V to 1.95 V		-	407	-	240	-	190	-	MHz
		V _{CC} = 2.3 V to 2.7 V		-	422	-	300	-	270	-	MHz
		V _{CC} = 3.0 V to 3.6 V		-	481	-	320	-	300	-	MHz

Symbol	Parameter	Conditions		T	amb = 25	°C	T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			-	Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 30	pF								-		
t _{pd}		CP to Q, \overline{Q} ; see Fig. 4.	[2]								
	delay	V _{CC} = 0.8 V		-	42.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.2	10.6	22.5	4.0	23.0	4.0	23.3	ns
		V _{CC} = 1.4 V to 1.6 V		3.7	7.2	12.0	3.7	13.3	3.7	14.0	ns
		V _{CC} = 1.65 V to 1.95 V		3.5	5.8	9.2	3.4	10.4	3.4	11.0	ns
		V _{CC} = 2.3 V to 2.7 V		3.3	4.7	6.6	3.0	7.3	3.0	7.8	ns
		V _{CC} = 3.0 V to 3.6 V		3.0	4.3	5.8	2.8	6.8	2.8	7.3	ns
		SD to Q, Q; see <u>Fig. 5</u> .	[2]								
		V _{CC} = 0.8 V		-	37.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.0	9.5	19.8	3.8	20.8	3.8	21.1	ns
		V _{CC} = 1.4 V to 1.6 V		3.8	6.7	10.9	3.7	12.0	3.7	12.7	ns
		V _{CC} = 1.65 V to 1.95 V		3.7	5.6	8.4	3.5	9.3	3.5	9.9	ns
		V _{CC} = 2.3 V to 2.7 V		3.7	4.8	6.6	3.2	7.2	3.2	7.6	ns
		V _{CC} = 3.0 V to 3.6 V		3.4	4.6	6.0	3.1	6.8	3.1	7.1	ns
		$\overline{R}D$ to Q, \overline{Q} ; see <u>Fig. 5</u> .	[2]								
		V _{CC} = 0.8 V		-	36.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.9	9.4	19.5	3.8	20.2	3.8	20.5	ns
		V _{CC} = 1.4 V to 1.6 V		3.6	6.6	10.9	3.7	12.0	3.7	12.6	ns
		V _{CC} = 1.65 V to 1.95 V		3.5	5.5	8.5	3.5	9.5	3.5	10.1	ns
		V _{CC} = 2.3 V to 2.7 V		3.5	4.7	6.5	3.2	7.1	3.2	7.6	ns
		V _{CC} = 3.0 V to 3.6 V		3.3	4.4	6.1	3.1	7.1	3.1	7.5	ns
f _{max}	maximum	CP; see <u>Fig. 4</u> .									
	frequency	V _{CC} = 0.8 V		-	28	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V		-	145	-	70	-	70	-	MHz
		V _{CC} = 1.4 V to 1.6 V		-	185	-	120	-	110	-	MHz
		V _{CC} = 1.65 V to 1.95 V		-	270	-	150	-	120	-	MHz
		V _{CC} = 2.3 V to 2.7 V		-	290	-	190	-	170	-	MHz
		V _{CC} = 3.0 V to 3.6 V		-	315	-	200	-	190	-	MHz

Symbol	Parameter	Conditions	T,	_{amb} = 25	°C	T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Мах	Min	Max	1
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF						-		
t _{su}	set-up time	D to CP HIGH; see Fig. 4.								
		V _{CC} = 0.8 V	-	3.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.6	-	1.2	-	1.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.3	-	0.6	-	0.6	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	0.5	-	0.5	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.2	-	0.4	-	0.4	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.3	-	0.4	-	0.4	-	ns
		D to CP LOW; see Fig. 4.								
		V _{CC} = 0.8 V	-	3.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.5	-	1.2	-	1.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.3	-	0.7	-	0.7	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	0.7	-	0.7	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.5	-	0.7	-	0.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.6	-	0.8	-	0.8	-	ns
t _h	hold time	D to CP; see Fig. 4.								
		V _{CC} = 0.8 V	-	-1.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	-0.3	-	0.5	-	0.5	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.2	-	0.2	-	0.2	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.2	-	0.1	-	0.1	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.1	-	0.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.2	-	0.1	-	0.1	-	ns
t _{rec}	recovery	RD; see <u>Fig. 5</u>								<u> </u>
	time	V _{CC} = 1.1 V to 1.3 V	-	-0.5	-	-0.9	-	-0.9	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.2	-	-0.6	-	-0.6	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.2	-	-0.4	-	-0.4	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.1	-	-0.1	-	-0.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	-0.1	-	-0.1	-	ns
		SD; see Fig. 5.								
		V _{CC} = 1.1 V to 1.3 V	-	-0.5	-	-0.3	-	-0.3	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.4	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.3	-	0	-	0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.1	-	0.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	_	-0.1	-	0.1	-	0.1	-	ns

Symbol	Parameter	Conditions		T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Мах	Min	Max	
t _W	pulse width	CP HIGH or LOW; see <u>Fig. 4</u> .								
		V _{CC} = 1.1 V to 1.3 V	-	2.1	-	2.7	-	2.7	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	1.1	-	1.5	-	1.5	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.9	-	1.6	-	1.6	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.6	-	1.7	-	1.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.6	-	1.9	-	1.9	-	ns
		SD or RD LOW; see <u>Fig. 5</u> .								
		V _{CC} = 1.1 V to 1.3 V	-	4.2	-	11.3	-	11.5	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	2.3	-	6.2	-	6.4	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	1.8	-	4.8	-	5.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	1.2	-	3.3	-	3.5	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	1.1	-	2.6	-	2.8	-	ns
C _{PD}	power dissipation	$ f_i = 1 \text{ MHz}; [3] $								
	capacitance	V _{CC} = 0.8 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	3.9	-	-	-	-	-	pF

Low-power D-type flip-flop with set and reset; positive-edge trigger

All typical values are measured at nominal V_{CC}. [1]

[2] [3]

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

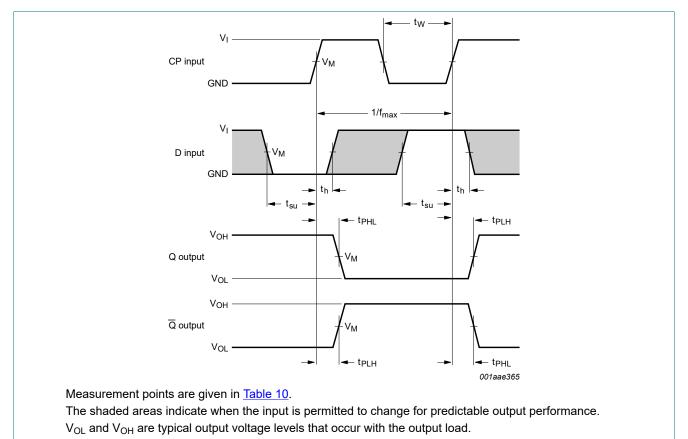
 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

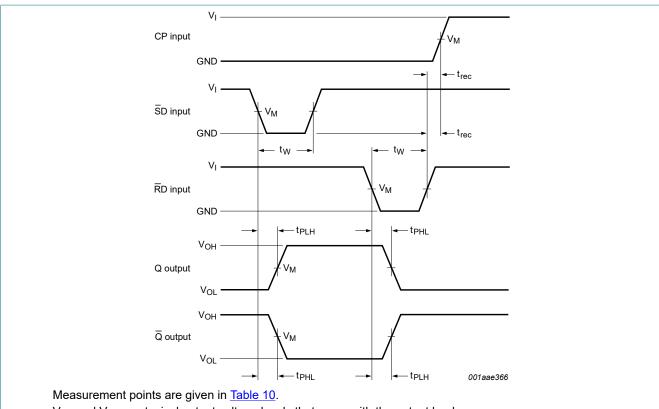
N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.



11.1. Waveforms and test circuit

Fig. 4. The clock input (CP) to output (Q, \overline{Q}) propagation delays, the data input (D) to clock input (CP) set-up and hold times and the clock input (CP) pulse width and maximum frequency

Low-power D-type flip-flop with set and reset; positive-edge trigger



 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 5. The set input (SD) and reset input (RD) to output (Q, Q) propagation delays, the set input (SD) and reset input (RD) pulse widths and the reset input (RD) to clock input (CP) recovery time

Table 10. Measurement points

Supply voltage	Output	Input					
V _{cc}	V _M	V _M	VI	t _r = t _f			
0.8 V to 3.6 V	$0.5 \times V_{CC}$	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns			

Low-power D-type flip-flop with set and reset; positive-edge trigger

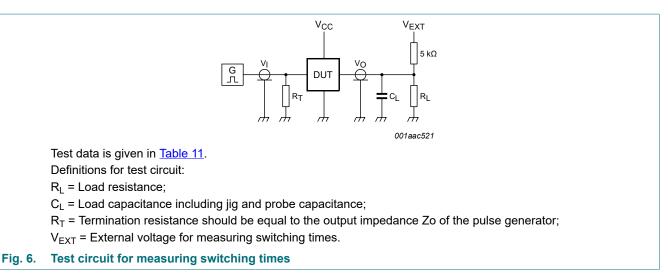


Table 11. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	C _L R _L [1] 1		t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12. Package outline

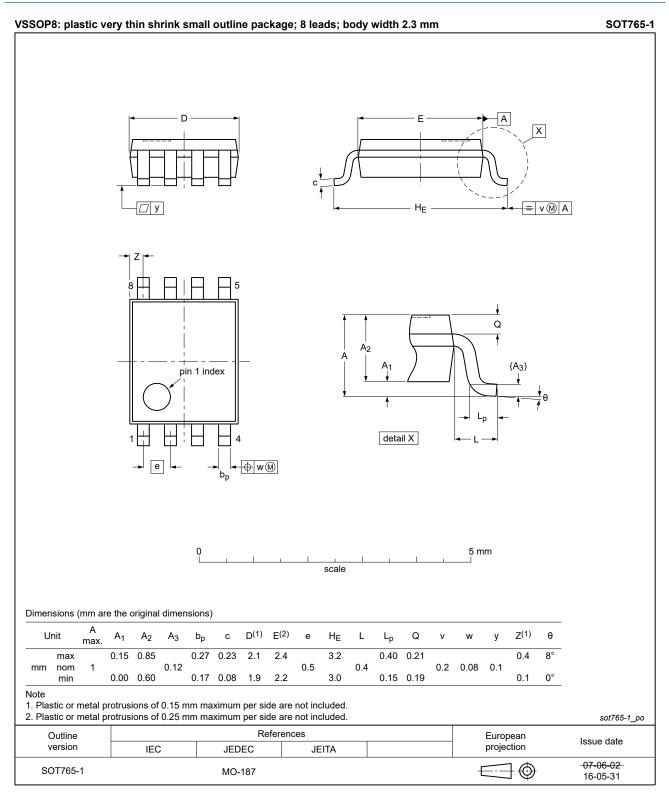


Fig. 7. Package outline SOT765-1 (VSSOP8)

13. Abbreviations

Table 12. Abbreviations						
Acronym	Description					
ANSI	American National Standards Institute					
CDM	Charged Device Model					
DUT	Device Under Test					
ESD	ElectroStatic Discharge					
ESDA	ElectroStatic Discharge Association					
HBM	Human Body Model					
JEDEC	Joint Electron Device Engineering Council					

14. Revision history

Table 13. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP1G74_Q100 v.4.1	20240809	Product data sheet	-	74AUP1G74_Q100 v.3			
74AUP1G74_Q100 v.4	20230714	Product data sheet	-	74AUP1G74_Q100 v.3			
Modifications:	Section 2 updat	ed.: ESD specification u	pdated according to	the latest JEDEC standard.			
74AUP1G74_Q100 v.3	20220620	Product data sheet	-	74AUP1G74_Q100 v.2			
Modifications:		s <mark>ection 2</mark> updated. Ig values for P _{tot} total po	wer dissipation have	e been updated.			
74AUP1G74_Q100 v.2	20170410	Product data sheet	-	74AUP1G74_Q100 v.1			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 						
74AUP1G74_Q100 v.1	20150527	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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